



Title	<i>Engineering Prototype Report for EP-54 – 2.75 W Charger/Adapter Using LNK520P (LinkSwitch)</i>
Specification	85-265 VAC Input, 5.5 V, 500 mA, 2.75 W Output
Application	Low Cost Charger / Adapter
Author	Power Integrations Applications Department
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Summary and Features

- Low cost, low component count battery charger/adapter – replaces linear transformer based solutions
- Optimized switching characteristics and low-side configuration of LNK520 minimizes EMI
 - Achieves greater than 10 dB μ V margin to composite conducted limits
 - No Y1 safety capacitor required for EMI compliance
 - Ultra-low earth leakage current, <5 μ A
- Small low cost EE16 transformer
 - Provision for EE13 transformer for smaller size
- Approximate constant voltage, constant current (CV/CC) primary sensed output characteristic
- Efficiency greater than 65% across all line/load conditions

The products and applications illustrated herein (including circuits external to the products and transformer construction) may be covered by one or more U.S. and foreign patents or potentially by pending U.S. and foreign patent applications assigned to Power Integrations. A complete list of Power Integrations' patents may be found at www.powerint.com.

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Important Note:

Although this board is designed to satisfy safety isolation requirements, the engineering prototype has not been agency approved. Therefore, all testing should be performed using an isolation transformer to provide the AC input to the prototype board.



1 Introduction

This document is an engineering report describing a 5.5 V, 500 mA charger/adapter power supply. The power supply utilizes the *LinkSwitch* LNK520 device, optimized for bias winding feedback. The *LinkSwitch* integrates a 700 V MOSFET, PWM controller, start-up, thermal shut-down, and fault protection circuitry. This power supply is a cost effective replacement of linear transformer based power supplies with the additional features of universal input range and high energy efficiency.

Compared to the LNK500, the optimized switching characteristics of the LNK520 and the low-side configuration provides improved EMI performance and less variation in EMI performance from design to design.

The document contains the power supply specification, schematic, bill of materials, transformer documentation, printed circuit layout, and performance data.

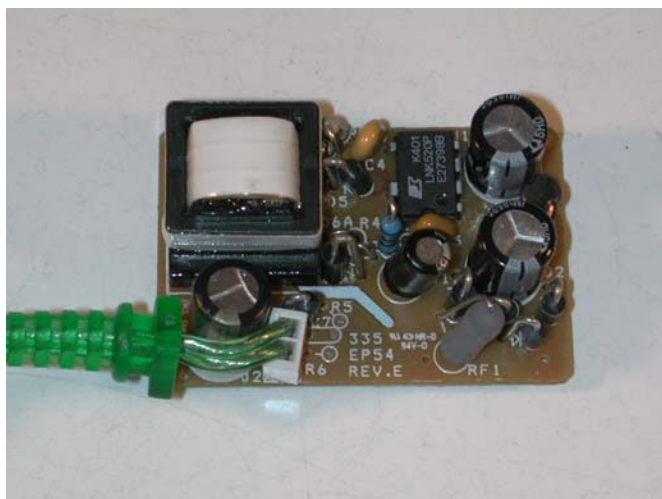


Figure 1 – Populated Circuit Board Photograph.

An alternate design utilizing simplified EE16 transformer construction is presented. See Appendix A for schematic, construction details and performance curves.



2 Power Supply Specification

Description	Symbol	Min	Typ	Max	Units	Comment
Input						
Voltage	V_{IN}	85		265	VAC	2 Wire – no protective ground.
Frequency	f_{LINE}	47	50/60	64	Hz	
No-load Input Power				0.3	W	Measured at 230 VAC + 10%
Output						
Output Voltage	V_{OUT}	5.0	5.5	6	V	± 20% (at peak power point)
Output Ripple (resistive load)	$V_{RIPPLE(R)}$		300		mV	Resistive load (peak power)
Output Ripple (battery load)	$V_{RIPPLE(B)}$		150		mV	Battery load (peak power)
Output Current	I_{OUT}	375	500	625	mA	± 25% (at peak power point)
Output Envelope						See figure 3
Total Output Power						
Continuous Output Power	P_{OUT}	2.06	2.75	3.43	W	
Efficiency	η	65			%	Measured at P_{OUT} (2.75 W), 25 °C
Environmental						
Conducted EMI		Meets CISPR22B / EN55022B				No Y1 Safety Capacitor
Safety		Designed to meet IEC950/UL1950				Class II
Surge		2			kV	1.2/50 μ s surge, IEC 1000-4-5, Series Impedance: Differential Mode: 2 Ω Common Mode: 12 Ω
Surge		2			kV	100 kHz ring wave, 500 A short circuit current, differential and common mode
Ambient Temperature	T_{AMB}	0		40	°C	In provided enclosure, free convection, sea level

Table 1 - EP54 Power Supply Specification.

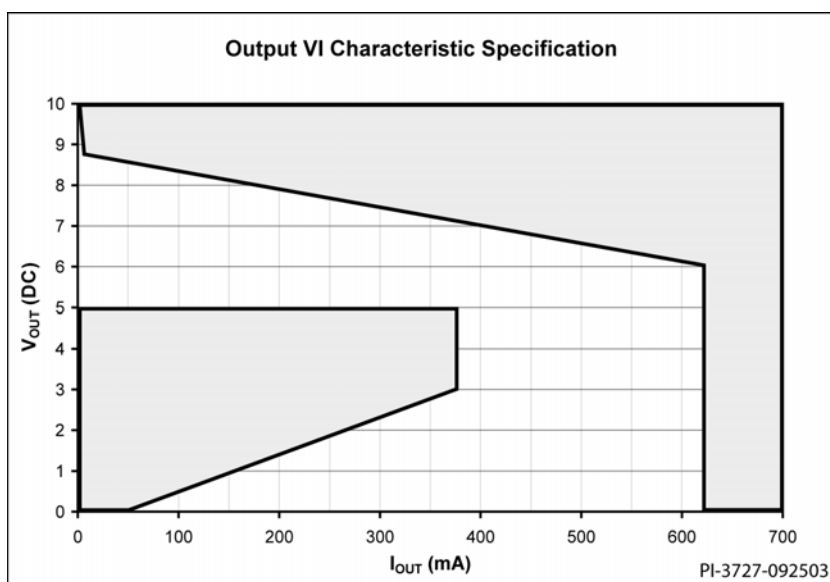
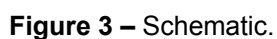


Figure 2- EP54 Output Characteristic Specification.



3 Schematic



4 Circuit Description

The circuit schematic shown in Figure 3 shows a design that provides a constant voltage / constant current (CV/CC) output characteristic from a universal input voltage range of 85 VAC-265 VAC. This design delivers 2.75 W with nominal peak power point voltage of 5.5 V and a current of 500 mA. The overall operating envelope is shown in Figure 10. The unit provides a CC operating range of $\pm 25\%$ over a case internal temperature range of 25 °C to 65 °C, and a transformer primary inductance tolerance of $\pm 10\%$.

Appendix A details the performance of a simplified EE16 transformer without using foil in the construction. This may be a more attractive design for some magnetics vendors but does result in a slight degradation in the CV regulation. See Appendix A for schematic, transformer construction and performance curves.

The PCB layout includes provisions to allow a transformer based on an EE13 bobbin to be fitted. An EE16 core size was selected for this design based on feedback that this is generally the lowest cost core size.

4.1 Input Stage and EMI Filtering

The bridge rectifier, D1-D4, rectifies the AC input and is smoothed by C1 and C2, with inductor L1 forming a π -filter to attenuate differential mode conducted EMI. Resistor RF1 is a fusible, flame proof type, providing protection from primary-side short circuits and line surges and provides additional differential EMI filtering. The switching frequency of 42 kHz allows such a simple EMI filter to be used without the need for a Y capacitor while still meeting international EMI standards.

It is recommended that RF1 be of wire wound construction to withstand input current surges while the input capacitor charges (metal film type are not recommended), and be compliant with safety flammability hazard requirements. Please consult your safety agency representative for requirements specific to your end-use application.

Capacitors C1 and C2 are sized to maintain a minimum DC voltage of around 90 V at the minimum AC input voltage. Their ESR should also be as low as possible to reduce differential mode EMI generation. The value of L1 is selected to give acceptable differential mode EMI attenuation with a current rating to meet the RMS input current at low line (or acceptable temperature rise). Conducted emissions in this design are compliant with EN55022B / CISPR 22B and FCC B limits with no input Y1 safety capacitor.

4.2 LinkSwitch Primary and Output Feedback

The LNK520P contains the necessary functions to implement start-up and auto-restart (output protection) operation, output constant voltage (CV) and constant-current (CC) control.



When power is applied, high voltage DC appears at the DRAIN pin of *LinkSwitch* (U1). The CONTROL pin capacitor C5 is then charged through a switched high voltage current source connected internally between the DRAIN and CONTROL pins. When the CONTROL pin reaches approximately 5.6 V relative to the SOURCE pin, the internal current source is turned off. The internal control circuitry is activated and the high voltage MOSFET starts to switch, using the energy in C5 to power the IC.

Once the output has reached regulation, PWM control maintains CV regulation by indirectly sensing the output winding voltage. Ideally the DC output voltage is equal to the bias voltage plus the forward drop of D6B multiplied by the transformer secondary winding to bias winding turns ratio minus the forward drop of D7. However, leakage inductance causes errors that vary with load, causing the output voltage to rise at no-load. To give the best regulation, the bias and secondary windings should be physically close to each other in the transformer.

Diode D6B rectifies the output of the bias winding, which is then smoothed by C3 to provide a DC voltage to be fed to the CONTROL pin via R4. Resistor R3 is added to filter noise due to leakage inductance. The value of R4 is set such that, at the peak power point, where the output is still in CV regulation, the CONTROL pin current is approximately 2.2 mA.

As the output load is increased, the peak power point (defined by $0.5 \times L \times I^2 \times f$) is exceeded. The output voltage and therefore primary side bias voltage reduce. The reduction in the bias voltage results in a proportional reduction of CONTROL pin current, which lowers the internal *LinkSwitch* current limit (current limit control).

Constant current (CC) operation controls secondary-side output current by reducing the primary-side current limit. The current limit reduction characteristic has been optimized to maintain an approximate constant output current as the output voltage and bias voltage is reduced.

If the load is increased further and the CONTROL pin current falls below approximately 0.8 mA, the CONTROL pin capacitor C5 will discharge and *LinkSwitch* will enter auto-restart operation.

Current limit control removes the need for any secondary-side current sensing components (sense resistor, transistor, optocoupler and associated components). Removing the secondary sense circuit dramatically improves efficiency, giving the associated benefit of reduced enclosure size.

Diode D5, C4, R1, and R2 form the primary clamp network. This limits the peak DRAIN voltage due to leakage inductance. Resistor R2 allows the use of a slow, low cost rectifier diode by limiting the reverse current through D5 when U1 turns on. The selection of a slow diode improves radiated EMI and also improves CV regulation, especially at no load.



4.3 Output Rectification

Output rectification is provided by Schottky diode D7. The low forward voltage provides high efficiency across the operating range. Low ESR capacitor C6 achieves minimum output ripple and maximizes operating efficiency.

5 PCB Layout

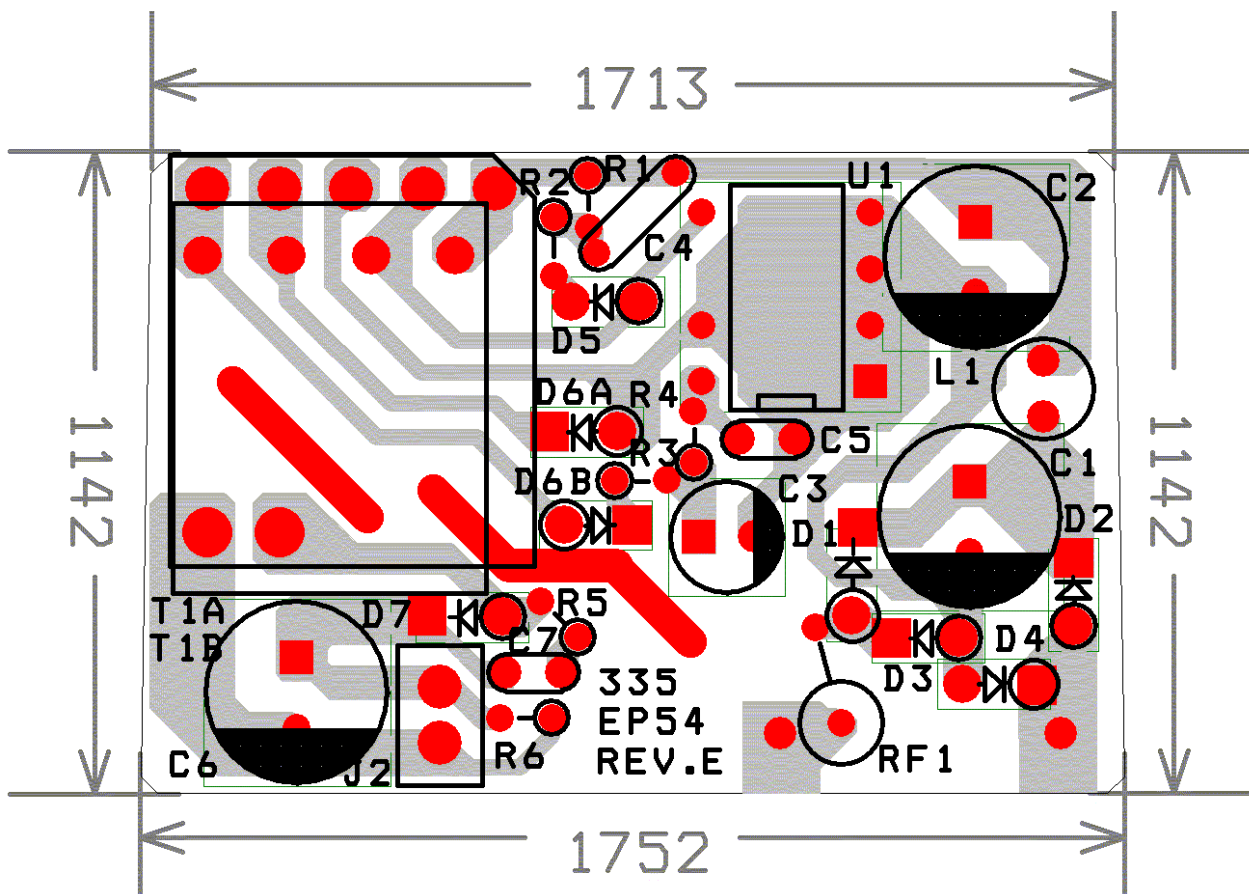


Figure 4 – EP-54 Printed Circuit Board Layout and Dimensions (0.001 inches)
(note: C7, R5 and R6 are not populated).

6 Bill Of Materials

Item	Qty	Reference	Description (Type)	P/N, Type	Manufacturer
1	1	U1	<i>LinkSwitch</i>	LNK520P	Power Integrations
2	2	C1, C2	4.7 μ F, 400 V (SHD Series)	380VB4R7M8X11C	Sam Young
			4.7 μ F, 380 V	380VB4R7M8X11L	UCC
3	1	C3	1 μ F, 50 V, general purpose	ECA-1HHG010	Panasonic (or generic)
4	1	C4	330 pF, 1000 V, Ceramic	ECK-D3A331KBP	Panasonic (or generic)
5	1	C5	220 nF, 50 V, Ceramic		Generic
6	1	C6	330 μ F, 16 V, 117 m Ω	EEU-FC1C331	Panasonic
7	4	D1-4	Rectifier 1 A, 600 V	1N4005,	Diodes, Inc. (or generic)
8	1	D5	Rectifier Glass Passivated	1N4007GP,	Generic
			1 A, 600 V		
9	1	D6B	1 A, 600 V, Fast recovery,	1N4937	Diodes, Inc.
			t_{rr} = 200 ns		(or generic)
10	1	D7	1 A, 60 V Schottky	11DQ06	International Rectifier
					(or generic)
11	1	J1	Jumper, 24 AWG, bare		Any
			(location D6A)		
12	1	L1	1.0 mH, 150 mA	SBCP-47HY102B	Tokin
13	1	RF1	8.2 Ω Fusible	CRF0414 253-4/8R2, 5%	Vitrohm
14	1	R1	390 k Ω , 1/4 W, 5%		Any
15	1	R2	100 Ω , 5%, 1/4 W		Any
16	1	R3	15 Ω , 5%, 1/2 W		Any
17	1	R4	6.81 k Ω (1%), 1/4 W		Any
18	1	T1	Custom EE16	LSLA40319B-1	L.S.E. http://www.lishin.com



7 Transformer Specification

Note: To correctly center the output voltage over a junction temperature of 25 °C to 65 °C (approx ambient 0 °C to 40 °C), the design software and design methodology may produce a slightly different transformer design than the one shown here.

7.1 Electrical Diagram

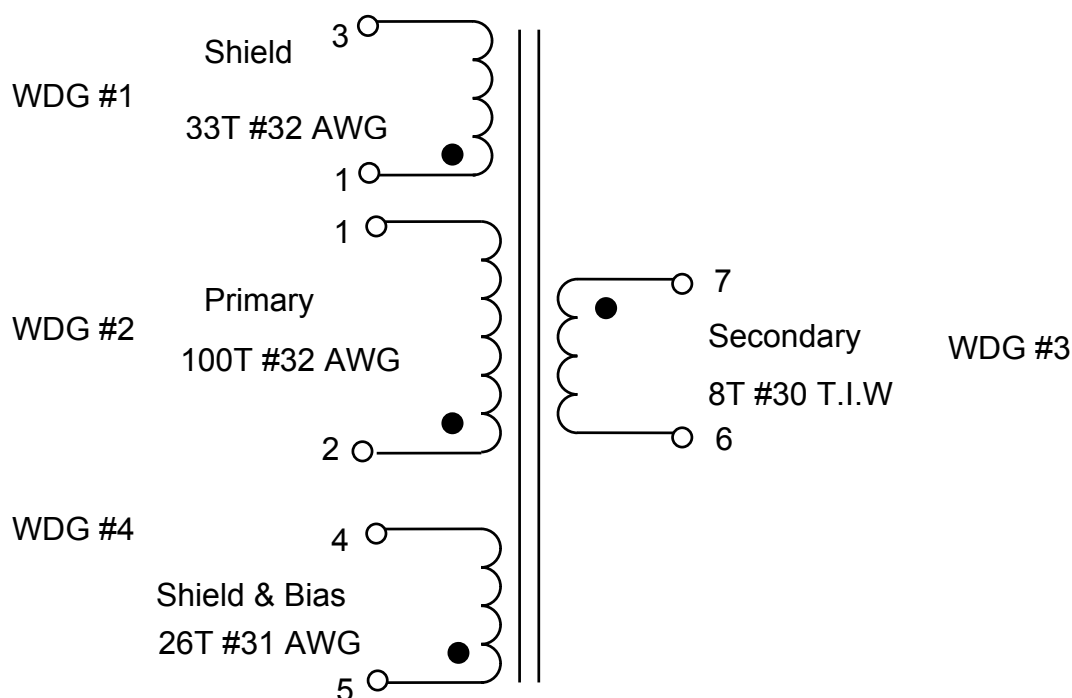


Figure 5 – Transformer Electrical Diagram.

7.2 Electrical Specifications

Electrical Strength	1 second, 60 Hz, from Pins 1-5 to Pins 6-10	3000 VAC
Primary Inductance	Pins 1-2, all other windings open, measured at 100 kHz, 0.4 VRMS	2.52 mH, +/-10%
Resonant Frequency	Pins 1-2, all other windings open	400 kHz (Min.)
Primary Leakage Inductance	Pins 1-2, with Pins 6-7 shorted, measured at 100 kHz, 0.4 VRMS	80 μ H (Max.)

7.3 Materials

Item	Description
[1]	Core: EE16, PC40EE16 TDK – A_{LG} 252 nH/T ²
[2]	Bobbin: Horizontal 10 pin (see Section 7.6)
[3]	Magnet Wire: #32 AWG, Please see note on next page
[4]	Foil: Tape Wrapped Copper Foil, 7.5 mm +/-0.1 mm wide by 0.05 mm/2 mil thick, 35 mm +/- 0.5 mm length – see additional drawing
[5]	Triple Insulated Wire: #30 AWG
[6]	Magnet Wire: #31 AWG, Please see note on next page
[7]	Tape: 3M 1298 Polyester Film (white) 322 mils (8.2 mm) wide by 2.2 mils thick
[8]	Tape: 3M 1298 Polyester Film (white) 291 mils (7.4 mm) wide by 2.2 mils thick
[9]	Tape: 3M 1298 Polyester Film (white) 586 mils (14.9 mm) wide by 2.2 mils thick
[10]	Tape: 3M 1298 Polyester Film (white) 196 mils (5.0 mm) wide by 2.2 mils thick
[11]	Barrier Tape: 2.0 mm wide, 0.15 mm thick, Please see the note on the next page
[12]	Barrier Tape: 2.25 mm wide, 0.15 mm thick, Please see the note on the next page
[13]	Glue AV118

Note: The transformer is an integral part of the EMI performance of this design. Changes to the transformer, even very minor, may have significant impact on both conducted and radiated EMI. More specific guidance is given below when attempting to repeat this transformer design.

1. Wire gauge selection for core cancellation, secondary and bias windings
 - The outside diameter of the wire can vary slightly due to variations in the insulation thickness although the bare copper area diameter is same.
 - Changing the wire gauge is acceptable to account for overall wire diameter differences. The wire gauge/size should be selected such that with the specified number of turns the winding completely fills one complete layer.
 - The bias winding can have the number of turns varied by up to 2 turns to make a complete layer if necessary but it is preferred to keep the turns as specified.
 - Winding information with wire gauge used should be indicated on sample report.
2. Primary winding
 - Use the same wire gauge/size as used for the core cancellation winding.
3. Barrier tape
 - Transformer vendors may have different thickness of barrier tape.
 - If the thickness is different, please make the height of the barrier tape the same or slightly higher than wire thickness used for that winding.



7.4 Transformer Build Diagram

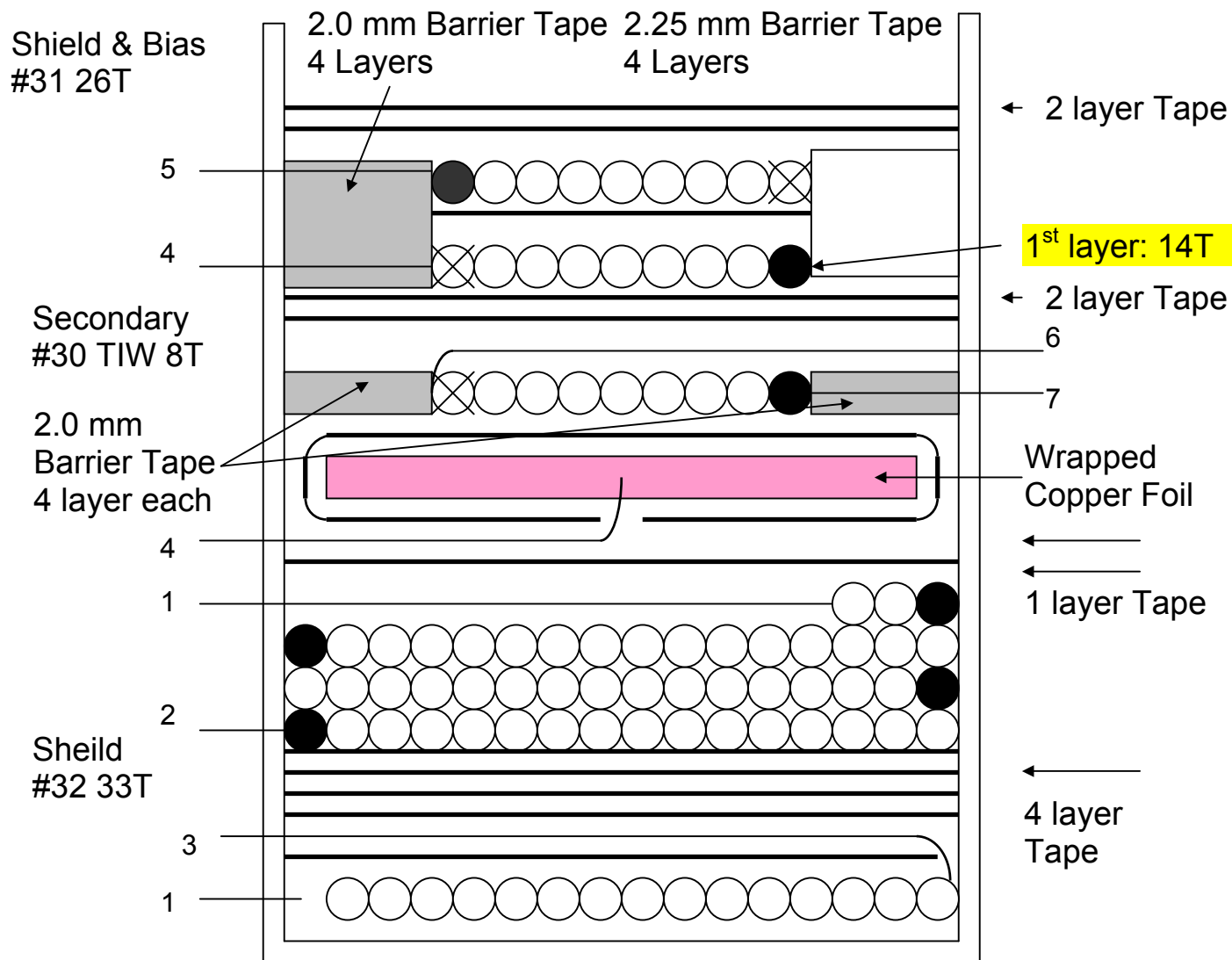


Figure 6a – Transformer Build Diagram.

KEY:

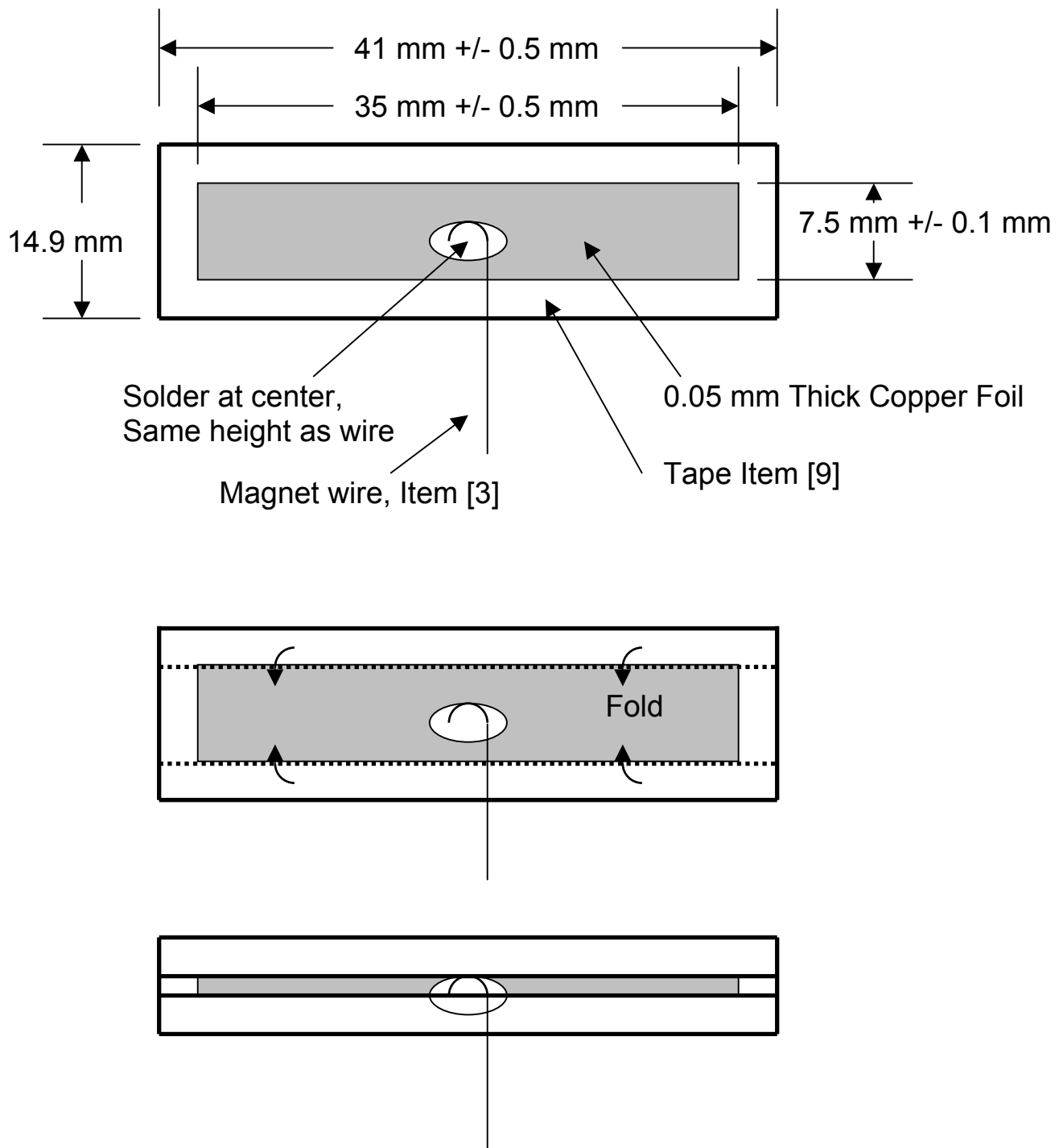


= Electrical phasing



= Mechanical start; reversed winding direction or same winding direction with bobbin rotated.



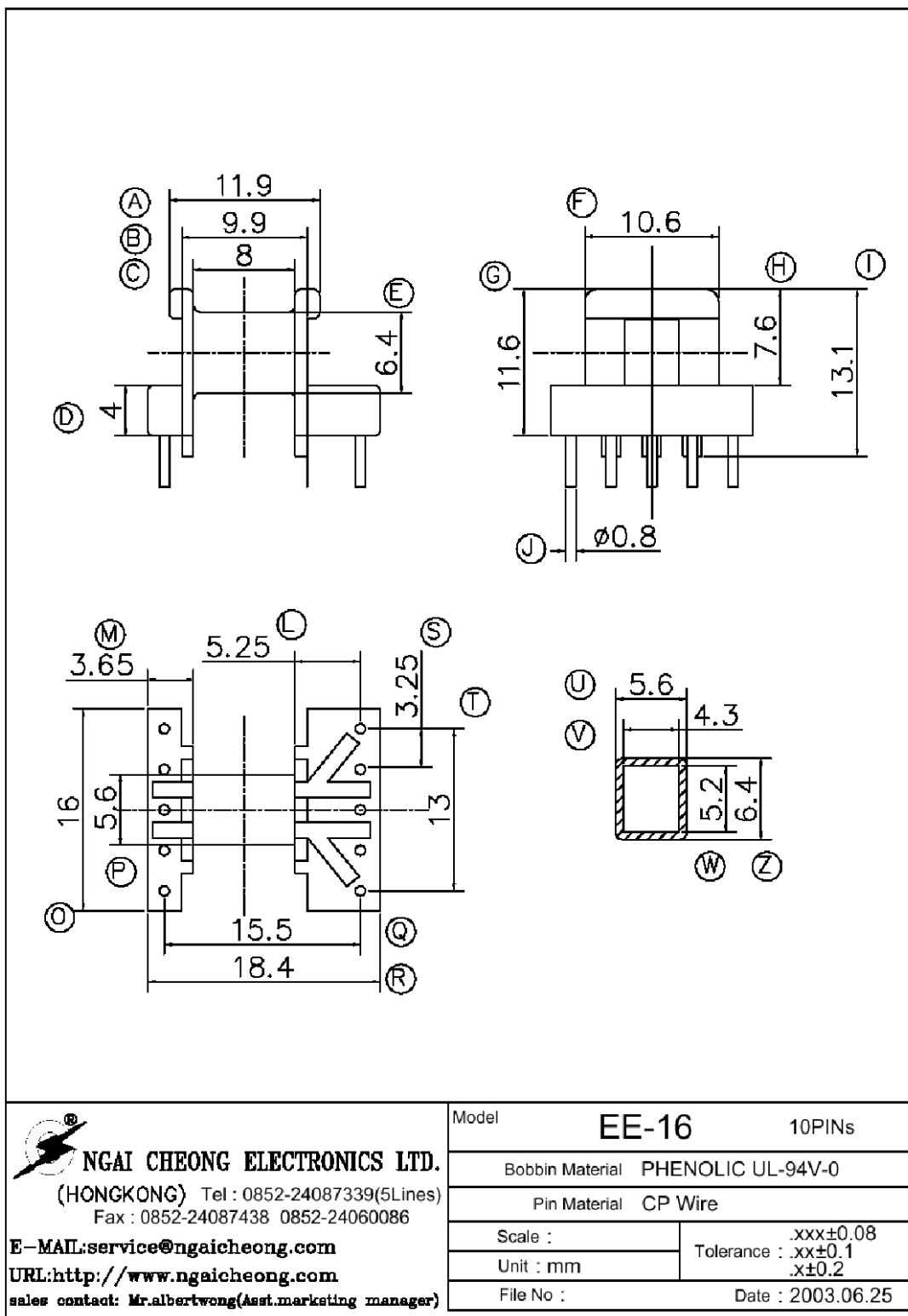
**Figure 6b – Foil Construction Diagram.**

7.5 Transformer Construction

Bobbin Preparation	Pull Pin 8-10 on bobbin [2] to provide polarization. Set bobbin with pins 1-5 on right hand side.
Shield Winding #1	Start at Pin 1. Wind 33 turns of item [3] from right to left in 1 layer across the entire width of the bobbin.
Basic Insulation	Temporarily terminate wire on left hand side of bobbin. Apply 1 layer of tape item [7].
Terminate Shield Winding #1	Terminate item [3] on pin 3. Cut pin 3 below termination to prevent contact with pcb trace.
Basic Insulation (continued)	Apply an additional 3 layers of tape item [7].
Primary Winding #2	Start at pin 2. Wind 100 turns of item [3] in 3 layers, plus 3 to 5 additional turns. Wind uniformly across the entire width of the bobbin with no empty space or gaps in any layer. Finish at pin 1.
Foil Shield	Assemble and apply foil shield [4] starting 3 mm from bottom side of bobbin [2]; such that foil termination wire aligns with pin 4. Insert the foil shield assembly [4] beneath a 10-15 mm long piece of tape (to hold in place). Wrap beneath 1 layer item [7] and terminate foil at pin 4.
Margin Tape	Apply 4 layers of item [11] on both sides of the bobbin ensuring no space to either bobbin wall.
Bobbin Preparation	Change the bobbin [2] orientation with pins 6-10 on right hand side. Maintain same spindle rotation direction.
Secondary Winding #3	Temporarily start at pin 1. Wind 8 turns item [5] in 1 layer from left to right. Wind uniformly across the entire width of the bobbin with no empty space or gaps in the layer. Finish at pin 7. Remove start from pin 1 and reattach to pin 6.
Basic Insulation	Apply 2 layers tape item [7].
Margin Tape L and R	Apply 4 layers of item [11] on left side of the bobbin ensuring no space to bobbin wall. Apply 4 layers of item [12] on right side of the bobbin ensuring no space to bobbin wall.
Bias Winding #4	Start at pin 4. Wind 14 turns item [6] from left to right. Wind uniformly across the entire width of the bobbin with no empty space or gaps in the layer.
Basic Insulation	Apply 1 layer of tape item [6], maintaining bias winding exit at edge of margin tape barrier.
Bias Winding #4 (continued)	Continue winding item [6] from right to left. Wind a total of 26 turns item [6]. Finish on pin 5.
Outer Insulation	Apply 2 layers of tape item [7].
Final Assembly	Assemble and secure core halves with item [12]. Dip varnish and cure (do not vacuum impregnate).



7.6 Transformer Bobbin Drawing



8 Performance Data

All measurements performed at room temperature, 60 Hz input frequency. Output voltage was measured at the end of the DC output cable. Input power was measured with a Yokogawa WT120 power meter.

8.1 Efficiency

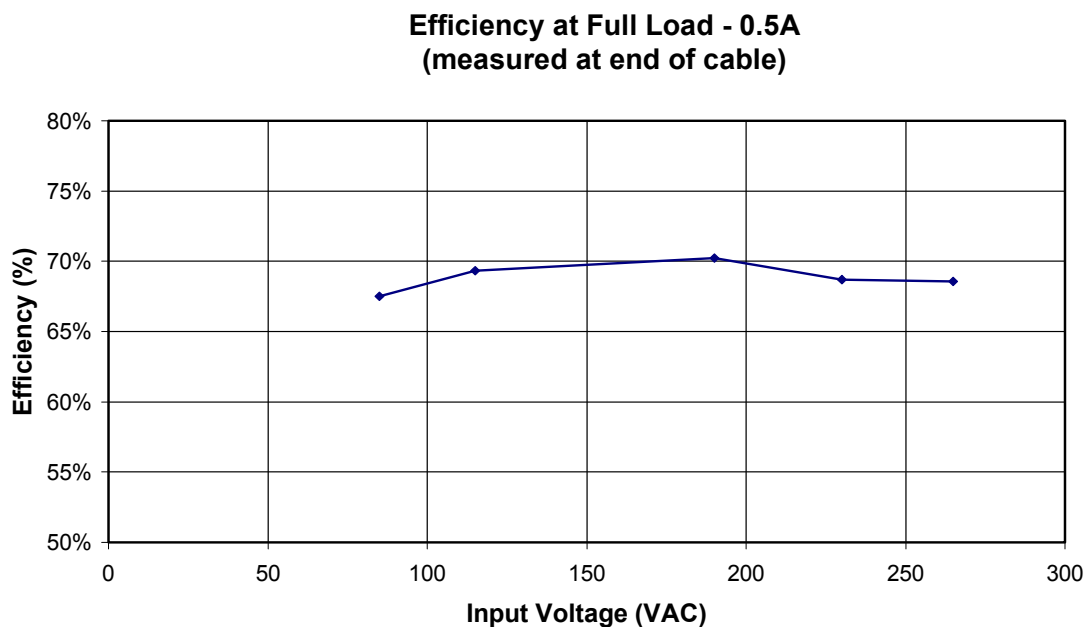


Figure 7 - Efficiency vs. Input Voltage, Room Temperature, 60 Hz.

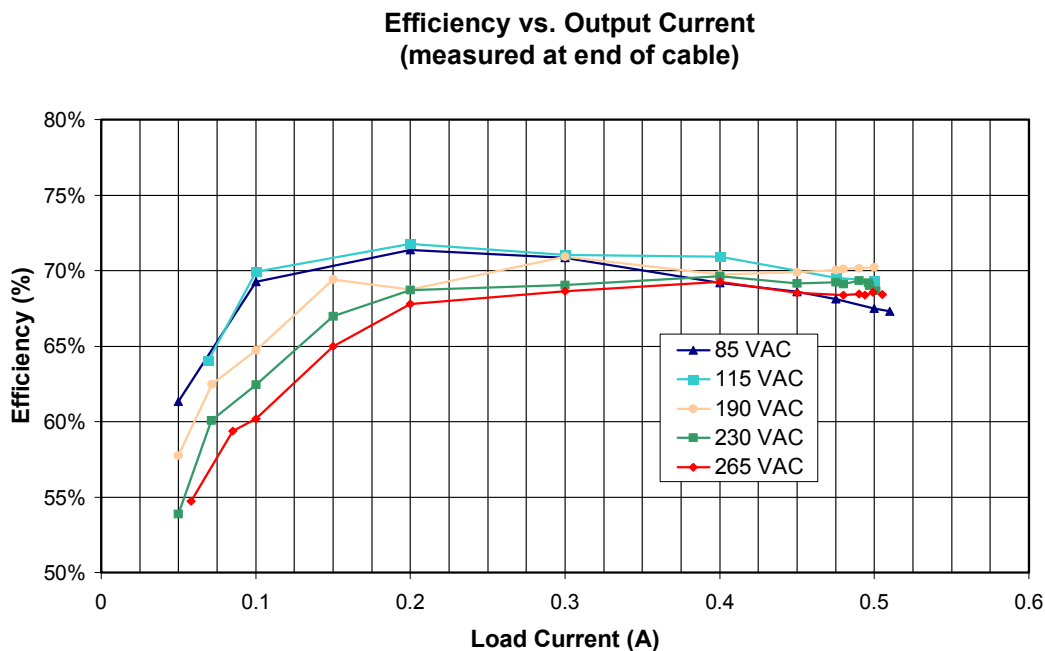


Figure 8 - Efficiency vs. Output Load, Room Temperature, 60Hz.



8.2 No-load Input Power

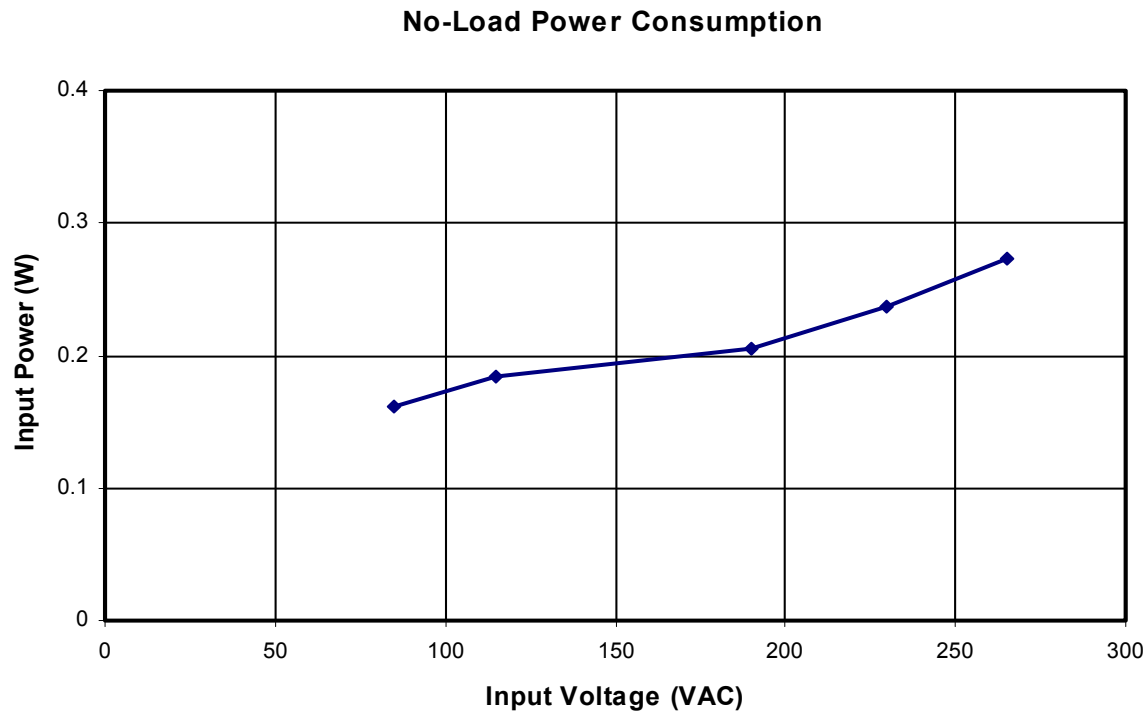


Figure 9 - Zero Load Input Power vs. Input Line Voltage, Room Temperature, 60 Hz.



8.3 8.3 Regulation

8.3.1 Line and Load

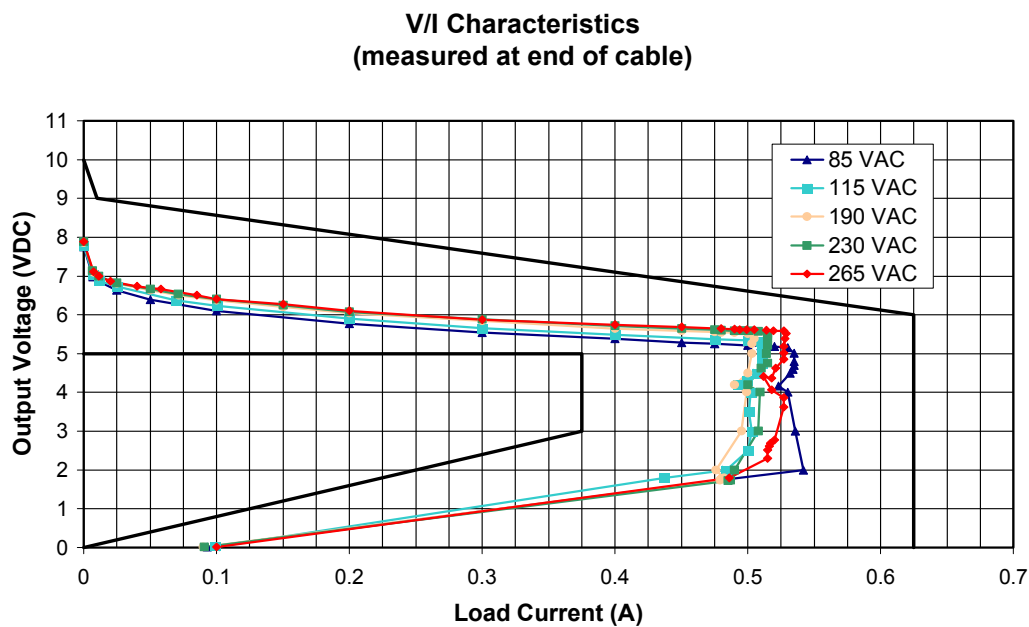


Figure 10 – Load Regulation, Room Temperature, 50 Hz.

8.4 Thermal Performance

The thermal images provide detail of the power supply operating component temperatures. The images were recorded after operating the unit for 12 hours at 85 VAC with an output load of 0.5 A at the maximum power point. This provides worst-case temperature rise on the *LinkSwitch* device.

The top image details component temperatures of the assembly with the case removed. Hotspots are visible at *LinkSwitch* and output diode locations, which reached 53 °C and 66 °C, respectively.

Operating within the closed case generated an internal temperature rise of +15 °C. This additional temperature rise gives a maximum *LinkSwitch* and output diode case temperatures of 68 °C and 81 °C at 24 °C ambient and 93 °C and 106 °C at 50 °C ambient. These results are well within acceptable operating limits.



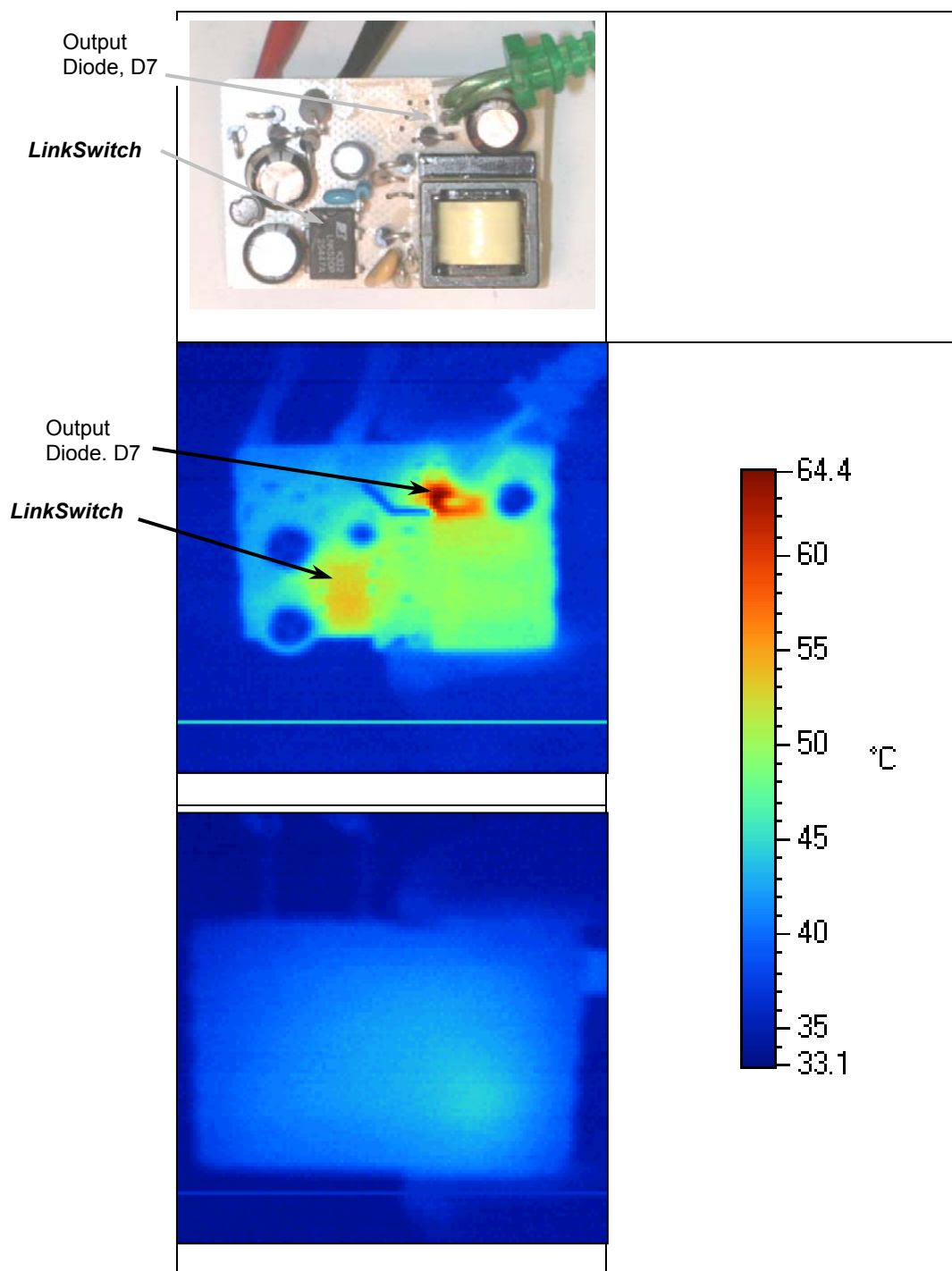


Figure 11 – Thermal Image Measurements of Board and Sealed Adapter, 85 VAC, 5.5 V at 0.5 A, 23 °C external ambient.

9 Waveforms

9.1 Drain Voltage and Current, Normal Operation

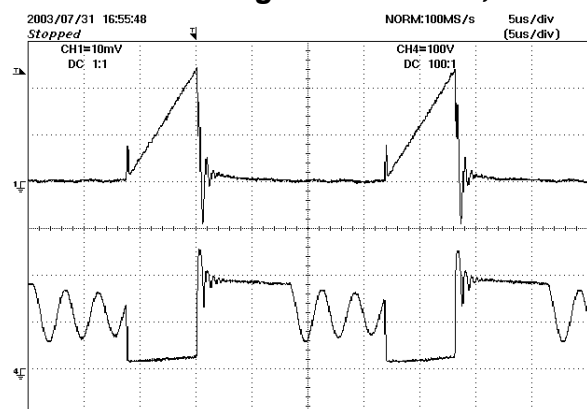


Figure 12 - 85 VAC, Full Load.

Upper: I_{DRAIN} , 0.1 A / div.

Lower: V_{DRAIN} , 100 V, 5 μ s / div.

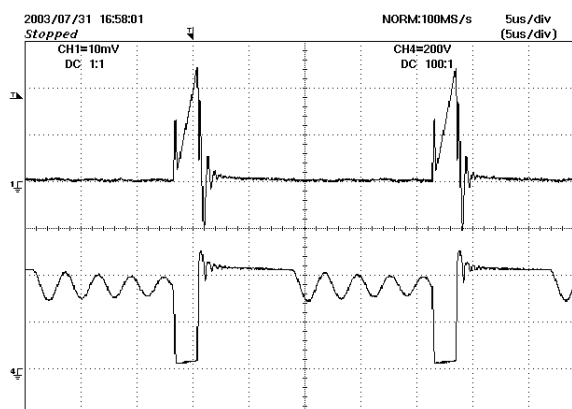


Figure 13 - 265 VAC, Full Load.

Upper: I_{DRAIN} , 0.1 A / div.

Lower: V_{DRAIN} , 200 V / div, 5 μ s / div.

9.2 Output Voltage Start-up Profile (Battery Load)

The power supply was started up into an output load simulating a battery. Resistor R_{LOAD} was reduced and confirmed start-up at voltages to 3 V. The battery model included series resistor value of 2.5 Ω (R_{LOAD}) and internal capacitor resistance of 0.5 Ω (R_{INT_RES}). The cable resistance R_{CABLE} was set to zero as the load was attached to the end of the actual output cable.

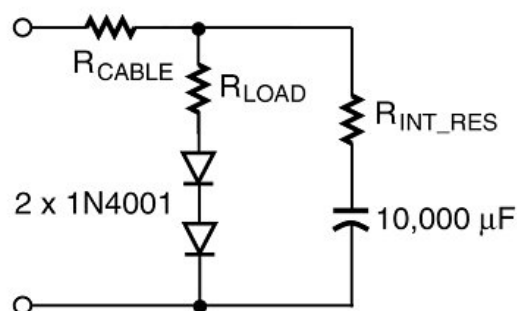


Figure 14 – Battery load model.

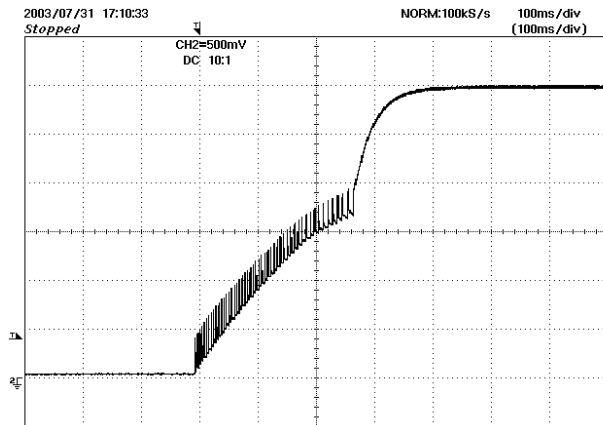


Figure 15 - Start-up Profile, 85 VAC.
0.5 V, 100 ms / div.

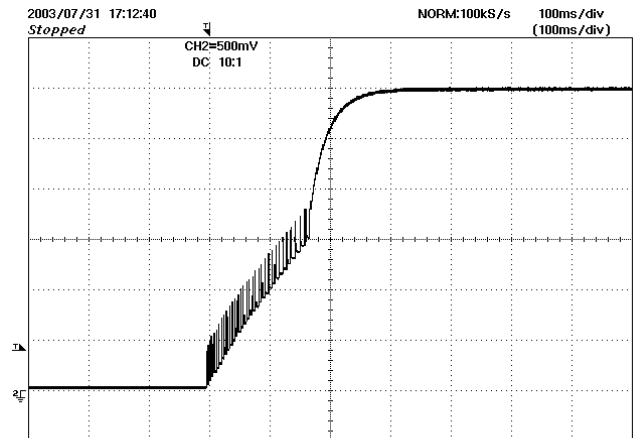


Figure 16 - Start-up Profile, 265 VAC.
0.5 V, 100 ms / div.

9.3 Drain Voltage and Current Start-up Profile

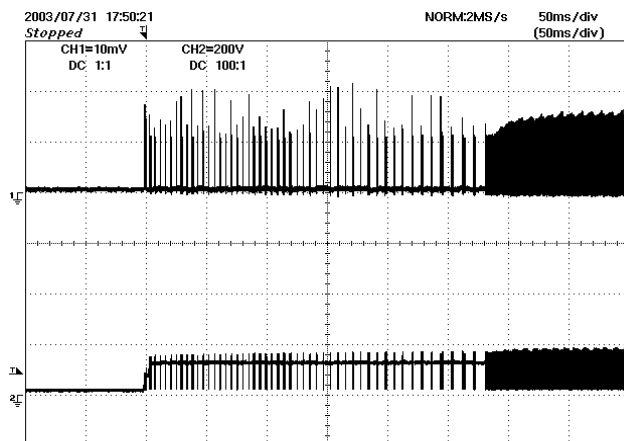


Figure 17 - 85 VAC Input and Maximum Load.
Upper: I_{DRAIN} , 0.1 A / div.
Lower: V_{DRAIN} , 100 V & 1 ms / div.

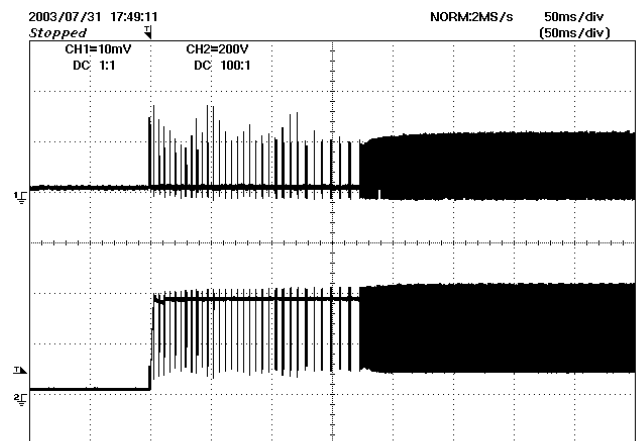


Figure 18 - 265 VAC Input and Maximum Load.
Upper: I_{DRAIN} , 0.1 A / div.
Lower: V_{DRAIN} , 200 V & 1 ms / div.



9.4 Load Transient Response (75% to 100% Load Step)

The oscilloscope was triggered using the load current step as a trigger source.

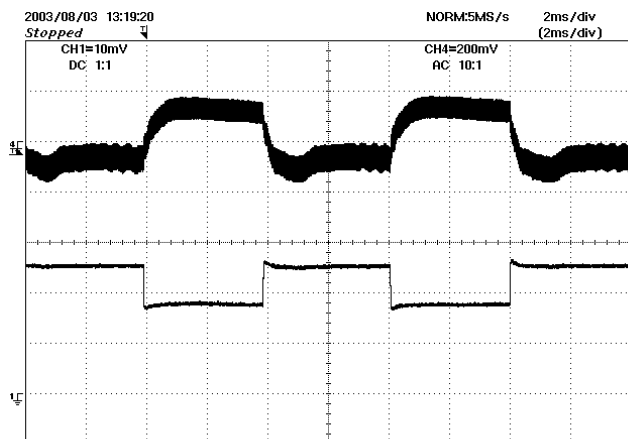


Figure 19 – Transient Response, 85 VAC, 75-100-75% Load Step.
Top: Output Voltage, 200 mV, 2 ms / div. (AC coupled)
Bottom: Load Current, 0.2 A / div. (DC coupled)

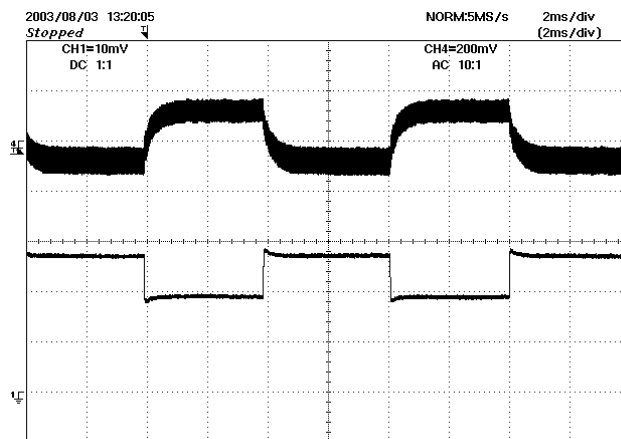


Figure 20 – Transient Response, 265 VAC, 75-100-75% Load Step.
Top: Output Voltage, 200 mV, 2 ms / div. (AC coupled)
Bottom: Load Current, 0.2 A / div. (DC coupled)

9.5 Output Ripple Measurements

9.5.1 Ripple Measurement Technique

For DC output ripple measurements, a modified oscilloscope test probe must be utilized in order to reduce spurious signals due to pickup. Details of the probe modification are provided in Figure 21 and Figure 22.

The 5125BA probe adapter is affixed with two capacitors tied in parallel across the probe tip. The capacitors include one (1) 0.1 μF /50 V ceramic type and one (1) 1.0 μF /50 V aluminum electrolytic. *The aluminum electrolytic type capacitor is polarized, so proper polarity across DC outputs must be maintained (see below).*

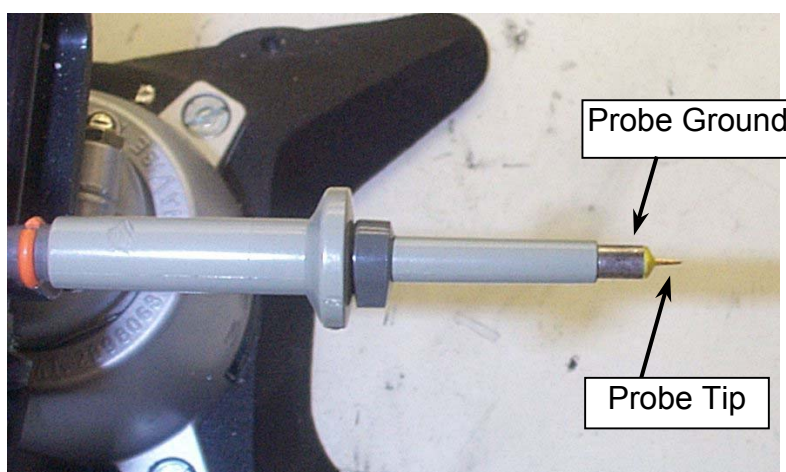


Figure 21 - Oscilloscope Probe Prepared for Ripple Measurement (End Cap and Ground Lead Removed).



Figure 22 - Oscilloscope Probe with Probe Master 5125BA BNC Adapter (Modified with Wires for Probe Ground for Ripple Measurement, and Two Parallel Decoupling Capacitors Added).

9.5.2 Ripple Measurement Results

All measurements were made with ripple probe at the end of the DC test cable. A resistive load was used in all cases.

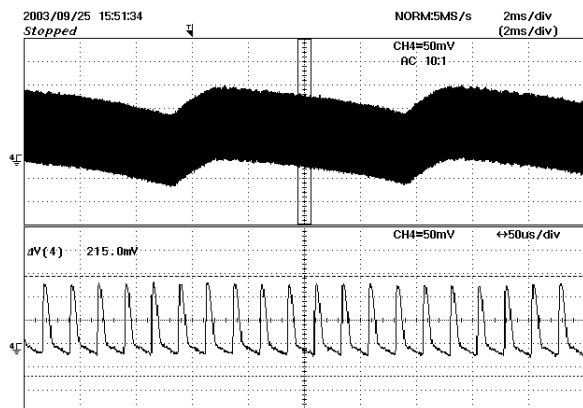


Figure 23 - Ripple, 85 VAC, Full Load.
2 ms, 50 mV / div.

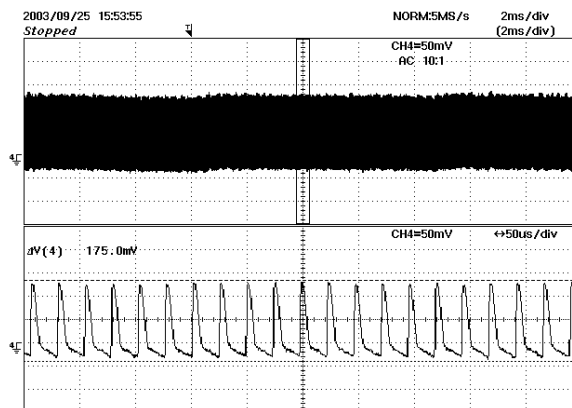


Figure 24 - Ripple, 230 VAC, Full Load.
2 ms, 50 mV / div.

10 Conducted EMI

Conducted emissions tests were completed at worst-case conditions: 230 VAC at full load, 5.5 V/0.5 A. Measurements with Artificial Hand connection are less than those with floating DC output load resistor. The output DC cable was included.

The test sample exhibits greater than 10 dB μ V margin below composite quasi-peak and average limits. This provides adequate margin to variation in transformer EMI characteristics. The results show significant attenuation in high frequency emissions.

Composite EN55022B / CISPR22B conducted limits are shown.

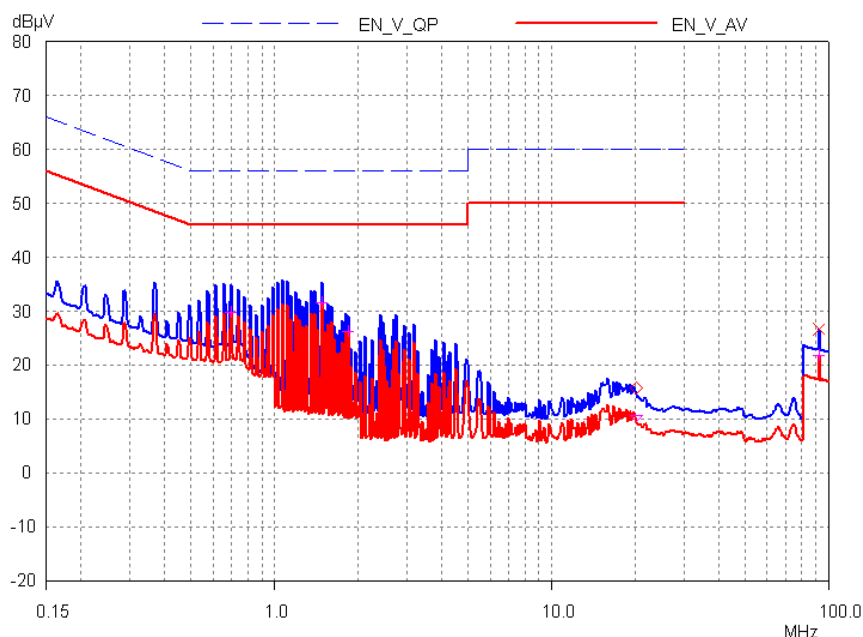
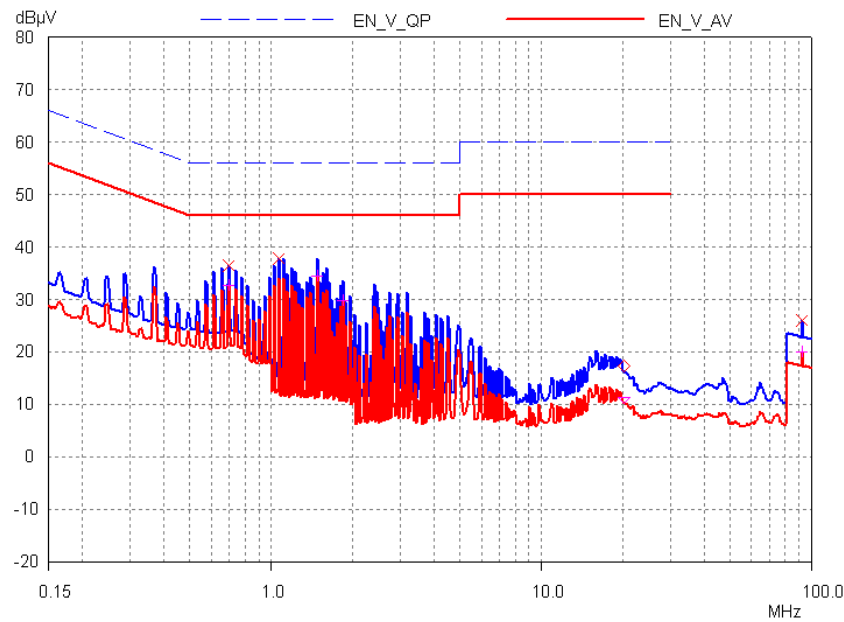


Figure 25 - Conducted EMI, 230 VAC, Maximum DC Load, with Artificial Hand Connected to Output Load.



**Figure 26 - Conducted EMI, 230 VAC, Maximum DC Load,
Output Load Floating.**

11 Appendix A: EE16 Simple, No Foil, Construction

11.1 Introduction

An alternative design utilizing an EE16 transformer with simplified construction is presented. The transformer uses integral bias and bifilar wound shields. These shields offer effective EMI attenuation with minimum additional transformer complexity.

Reduced coupling between bias and secondary windings increases load regulation and no-load output voltage. A secondary snubber is required to reduce high frequency EMI. Efficiency is increased from 66% to 70%, due to a reduction in transformer primary-to-secondary leakage inductance.

Appendix A presents schematic, bill of materials, transformer construction details and limited performance curves (including conducted EMI).

All specification requirements are identical to those presented in Section 2. Unless specified, the performance of this prototype is similar to those presented earlier; including output ripple, waveforms and thermal performance.

11.2 Schematic

The alternative EE16 transformer design is pin compatible with the EP-54 printed circuit board. Bias rectifier (D6B) and jumper (J1) are exchanged to maximize performance of the transformer bias shield. In addition, transformer primary shield (pin 3) is tied to bulk DC return.

Component value changes are required to filter the increased leakage spike seen on the primary bias winding. This includes the clamp circuit (R1, C4) and primary bias circuitry (R3, R4). Component additions include secondary snubber circuit (R5, C7) and preload resistor (R6).

11.3 Bill of Materials

Highlighted items are changes to previous design

Item	Qty	Reference	Description (Type)	P/N, Type	Manufacturer
1	1	U1	<i>LinkSwitch</i>	LNK520P	Power Integrations
2	2	C1, C2	4.7 μ F, 400 V (SHD Series) 4.7 μ F, 380 V	380VB4R7M8X11C 380VB4R7M8X11L	Sam Young UCC
3	1	C3	1 μ F, 50 V, general purpose	ECA-1HHG010	Panasonic (or generic)
4	1	C4	1000 pF, 1000 V	Ceramic	Any
5	1	C5	220 nF, 50 V	Ceramic	Any
6	1	C6	330 μ F, 16 V, 117 m Ω	EEU-FC1C331	Panasonic
7	1	C7	470 pF, 50 V	Ceramic	Generic
8	4	D1-4	Rectifier 1 A, 600 V	1N4005	Diodes, Inc. (or generic)
9	1	D5	Rectifier Glass Passivated 1 A, 600 V	1N4007GP	Any – generic
10	1	D6A	1 A, 600 V, Fast recovery, t_{rr} = 200 ns	1N4937	Diodes, Inc. (or generic)



11	1	D7	1 A, 60 V Schottky	11DQ06	International Rectifier (or generic)
12	1	J1	Jumper, 24 AWG, bare (location D6B)		Generic
13	1	L1	1.0 mH, 150 mA	SBCP-47HY102B	Tokin
14	1	RF1	8.2 Ω Fusible	CRF0414 253-4/8R2, 5%	Vitrohm
15	1	R1	200 kΩ, 1/4 W		Generic
16	1	R2	100 Ω , 1/4 W		Generic
17	1	R3	200 Ω, 1/4 W		Generic
18	1	R4	5.9 kΩ (1%), 1/4 W		Generic
19	1	R5	51 Ω, 1/4 W		Generic
20	1	R6	5.1 kΩ, 1/4 W		Generic
21	1	T1	Custom EE16	SIL6027D	HiCal www.hical.com



11.4 Transformer Specification

11.4.1 Transformer Winding

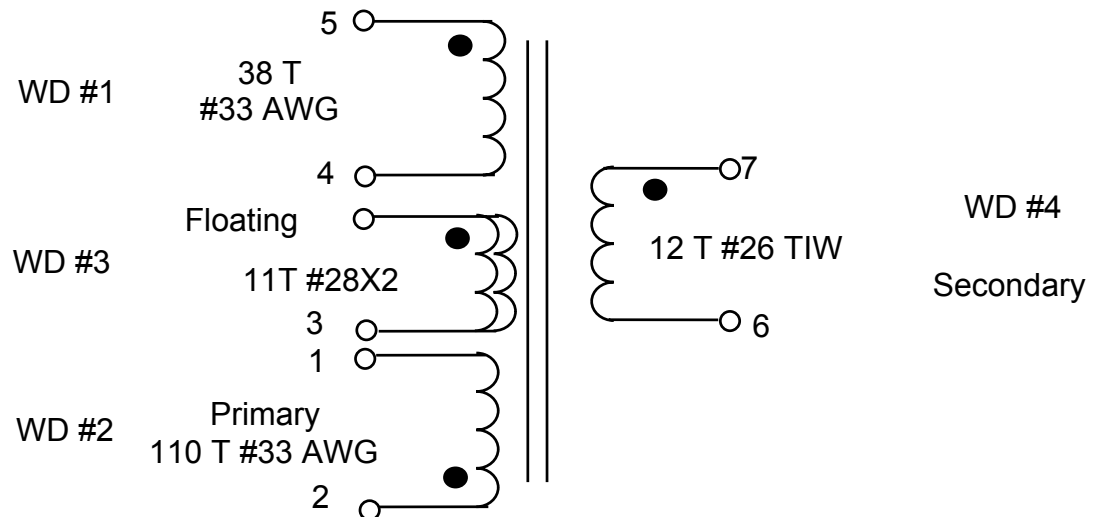


Figure 27 – Transformer Electrical Diagram, Alternate EE16.

11.4.2 Electrical Specifications

Electrical Strength	60Hz 1minute, from Pins 1-5 to Pins 6-7	3000 VAC
Primary Inductance (Pin 1 to Pin 3)	All windings open	2.73 mH +/- 10%
Resonant Frequency	All windings open	510 kHz (Min.)
Primary Leakage Inductance	Pins 6-7 shorted	60 μ H (Max.)

11.4.3 Transformer Build Diagram

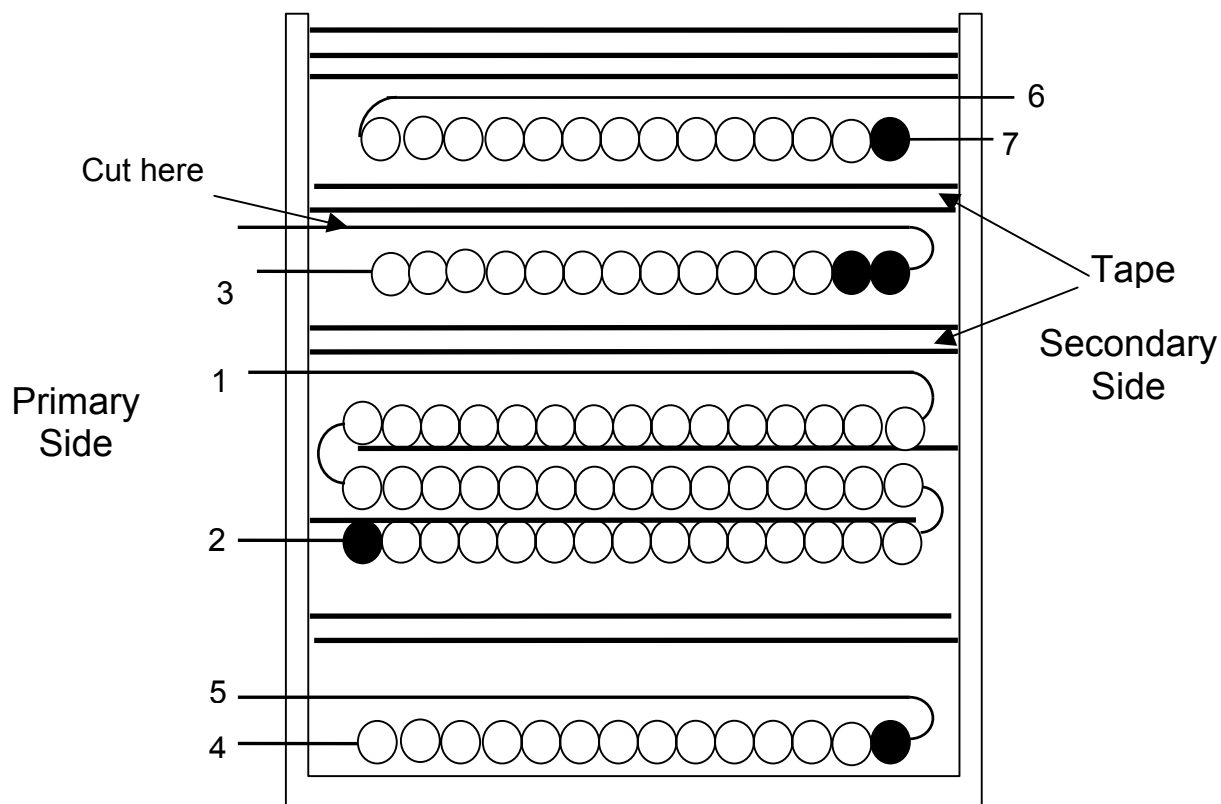


Figure 28 – Transformer Build Diagram,
Alternate EE16.

11.5 Performance Data

All measurements performed at room temperature, 60 Hz input frequency. Output voltage was measured at the end of the DC output cable. Input power was measured with a Yokogawa WT120 power meter.



11.5.1 Efficiency

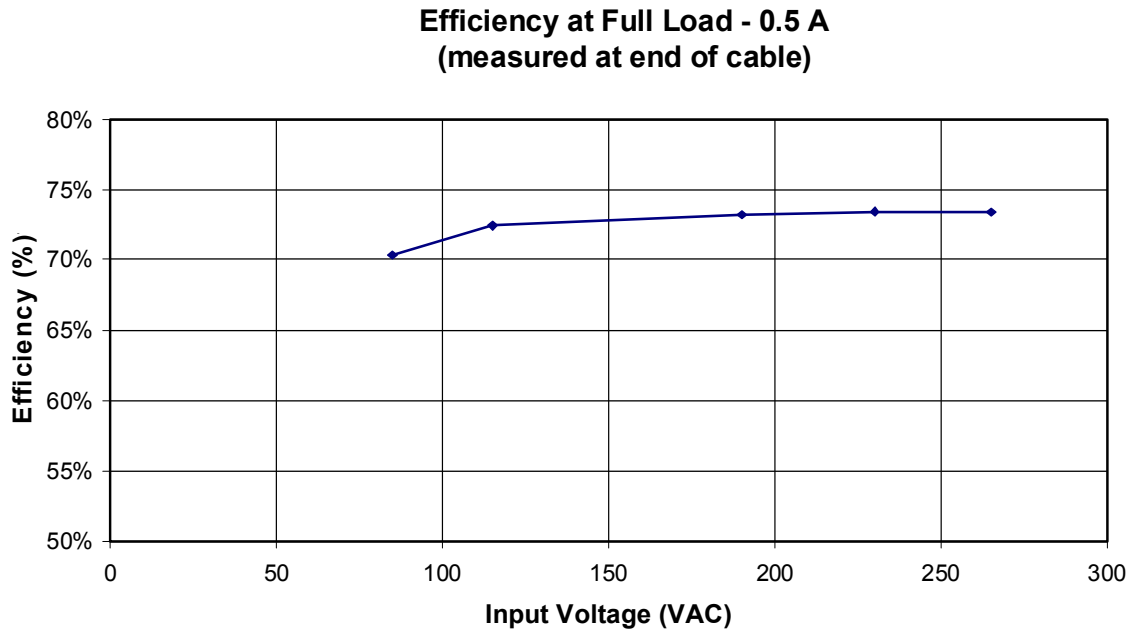


Figure 29 – Efficiency vs. Input Voltage, Alternate EE16, Full Load, Room Temperature, 60Hz.

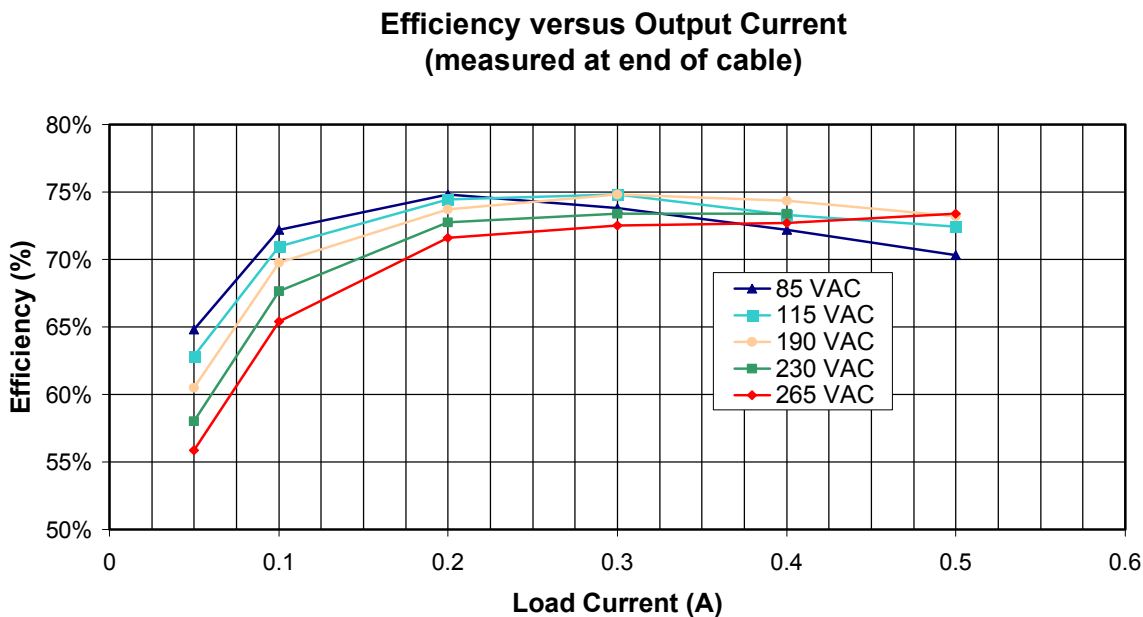


Figure 30 – Efficiency vs. Output Load, Alternate EE16, Room Temperature, 60Hz.



11.5.2 Line and Load Regulation

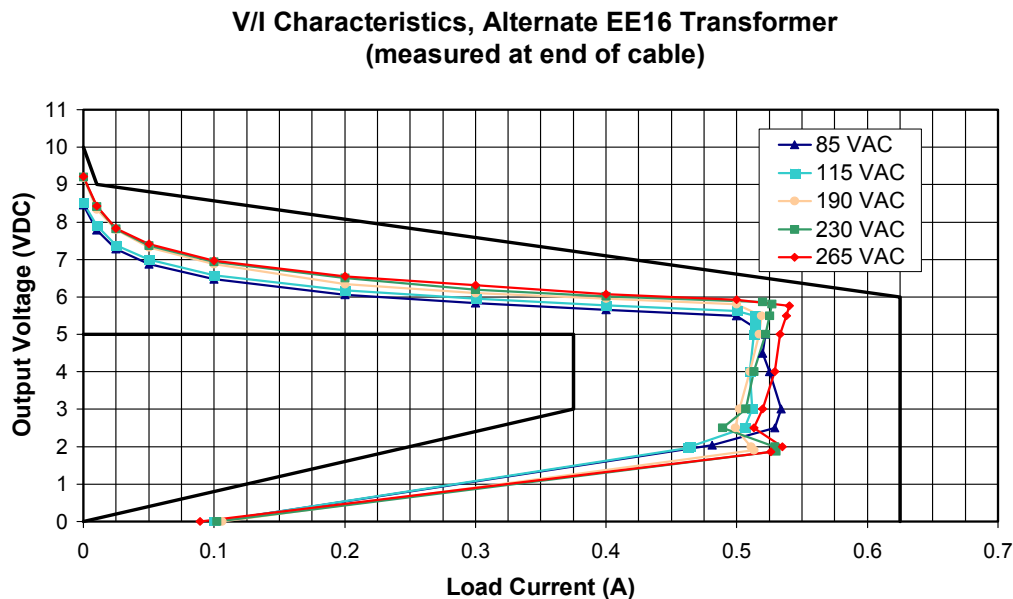


Figure 31 – Line and Load Regulation, Alternative EE16 Transformer Design.

11.6 Conducted EMI

Conducted emissions were measured at the peak output power point at worst-case nominal line voltage, 230 VAC.

Measurements consider both artificial hand (connected to DC output load terminal) and floating outputs. DC cable harness was included.

The test sample exhibits greater than 10 dB μ V margin below composite Quasi-peak and Average limits. This provides adequate margin to variation in transformer EMI characteristics. The results show significant attenuation in high frequency emissions.

Composite EN55022B / CISPR22B conducted limits are shown.



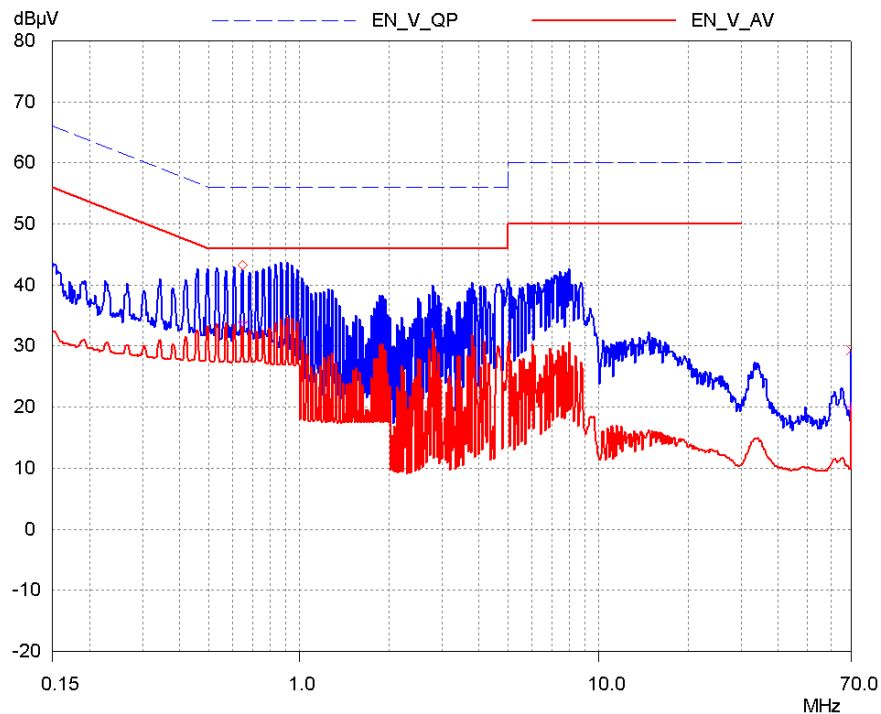


Figure 32 – Conducted EMI, Alternative EE16 Transformer design, 230 VAC, Maximum DC Load, with Artificial Hand.

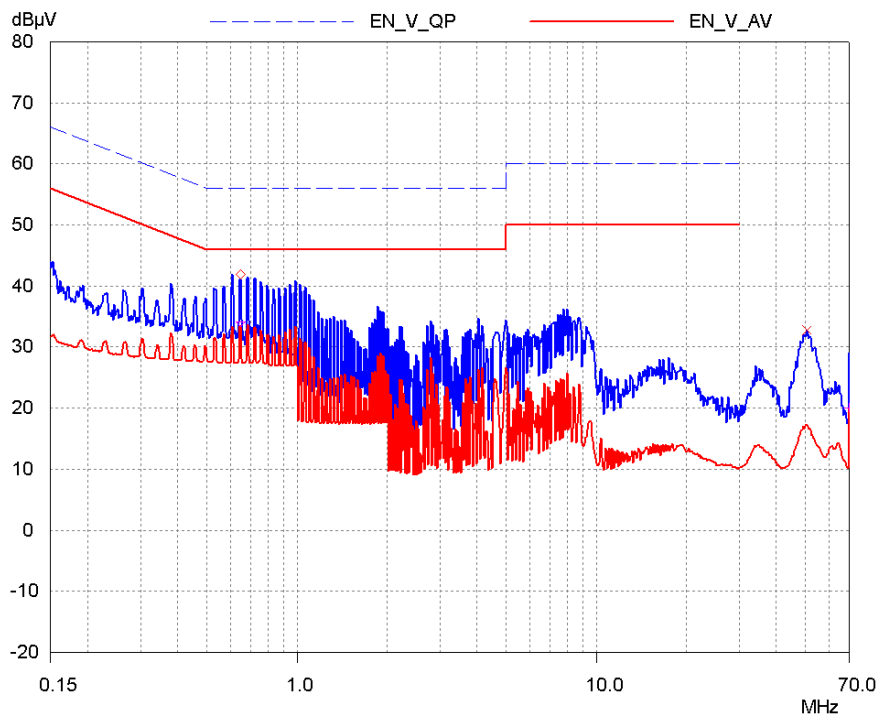


Figure 33 – Conducted EMI, Alternative EE16 Transformer, 230 VAC, Maximum DC Load, Floating Output.

12 Revision History

Date	Author	Revision	Description & changes
29-Sept-2003	SH	0.1	First Draft
01-Oct-2003	PV	0.2	Second Draft (Edits)
25-Feb-2004	PV	1.0	Third Draft (Photo)
07-May-2004	SH	1.1	Thermal Image (Labels)



NOTES



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